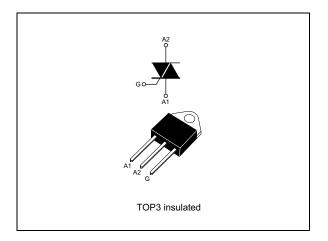


TPDVxx40

40 A high voltage Triacs

Datasheet - production data



Features

- On-state current (I_{T(RMS)}): 40 A
- Max. blocking voltage (V_{DRM}/V_{RRM}): 1200 V
- Gate current (I_{GT}): 200 mA
- Commutation at 10 V/µs: up to 142 A/ms
- Noise immunity: 500 V/µs
- Insulated package:
 - 2,500 V rms (UL recognized: E81734)

Description

The TPDVxx40 series use a high performance alternistor technology. Featuring very high commutation levels and high surge current capability, this family is well adapted to power control on inductive load (motor, transformer...).

Table	1.	Device	summary

Parameter	Blocking voltage V _{DRM} /V _{RRM}	On-state current I _{T(RMS)}	Gate current I _{GT}
TPDV640RG	600 V		
TPDV840RG	G 800 V 40 A 2		200 mA
TPDV1240RG	1200 V		

This is information on a product in full production.

1 Characteristics

Symbol	Parameter			Value	Unit
I _{T(RMS)}	On-state rms current (180° conduction a	ingle)	T _c = 75 °C	40	А
	Non repetitive surge peak on-state	t _p = 2.5 ms		590	A
I _{TSM}		t _p = 8.3 ms	T _j = 25 °C	370	
		t _p = 10 ms		350	
l ² t	I ² t value for fusing	t _p = 10 ms	T _j = 25 °C	610	A ² S
dl/dt	Critical rate of rise of on-state current	Repetitive F =	Repetitive F = 50 Hz		A/µs
unut	$I_G = 500 \text{ mA}; \text{dI}_G/\text{dt} = 1 \text{ A}/\mu\text{s}$	Non repetitive	Non repetitive		
		TPDV640	T _j = 125 °C	600	V
V _{DRM} V _{RRM}	Repetitive peak off-state voltage	TPDV840		800	
		TPDV1240		1200	
T _{stg} T _j	Storage junction temperature range Operating junction temperature range			-40 to +150 -40 to +125	°C
TL	Maximum lead temperature for soldering during 10 s at 2 mm from case			260	°C
V _{INS(RMS)} ⁽¹⁾	Insulation rms voltage			2500	V

1. A1, A2, gate terminals to case for 1 minute

Table 3. Electrical Characteristics ($T_j = 25$ °C, unless otherwise specified)

Symbol	Test condition		Quadrant		Value	Unit
I _{GT}			- -	Max.	200	mA
V _{GT}	V _D = 12 V DC, R _L = 33 Ω		1 - 11 - 111	Max.	1.5	V
V _{GD}	$V_D = V_{DRM} R_L = 3.3 k\Omega$	T _j = 125 °C	- -	Min.	0.2	V
t _{gt}	$V_D = V_{DRM} I_G = 500 \text{ mA } dI_G/dt =$	3A/µs	- -	Тур.	2.5	μs
I _H ⁽¹⁾	I _T = 500 mA Gate open			Тур.	50	mA
			-	Turn	100	m۸
IL I	$I_{G} = 1.2 \times I_{GT}$		II	Тур.	200	mA
dV/dt	Linear slope up to : $T_j = 125 \degree C$ $V_D = 67\% V_{DRM}$ Gate open $T_j = 125 \degree C$			Min.	500	V/µs
V _{TM} ⁽¹⁾	I _{TM} = 56 A t _p = 380 μs		Max.	1.8	V	
I _{DRM}	V V	T _j = 25 °C		Max.	20	μA
I _{RRM}				ινιαλ.	8	mA
(dl/dt)c ⁽¹⁾	(dV/dt)c = 200 V/µs			Min.	35	A/ma
	(dV/dt)c = 10 V/µs	– T _j = 125 °C		IVIIII.	142	A/ms

1. For either polarity of electrode A_2 voltage with reference to electrode A_1 .

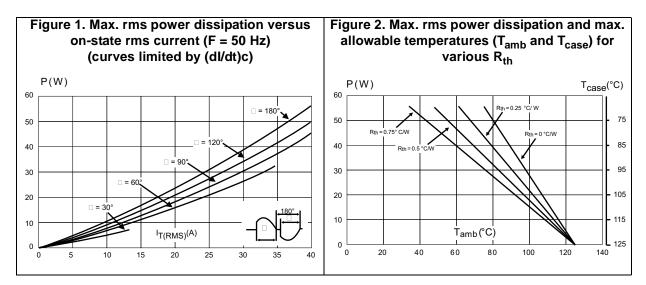


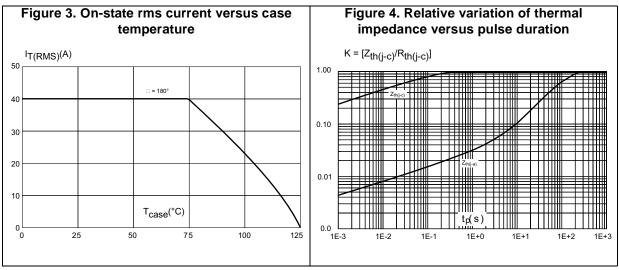
Symbol	Parameter	Value	Unit		
P _{G(AV)}	Average gate power dissipation	1	W		
P _{GM}	Peak gate power dissipation $t_p = 20 \ \mu s$		40	W	
I _{GM}	Peak gate current $t_p = 20 \ \mu s$		8	A	
V _{GM}	Peak positive gate voltage	t _p = 20 μs	16	V	

Table 4. Gate characteristics (maximum values)

Table 5. Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-a)}	Junction to ambient	50	°C/W
R _{th(j-c)} DC	Junction to case for DC	1.2	°C/W
R _{th(j-c)} AC	Junction to case for 360 °conduction angle (F = 50 Hz)	0.9	°C/W







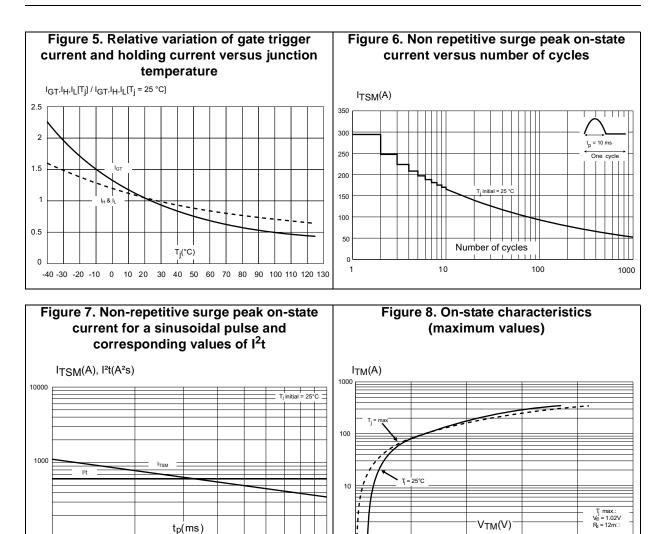
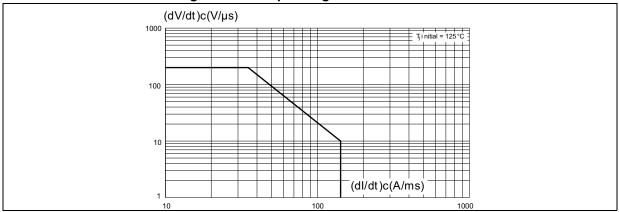


Figure 9. Safe operating area below curve



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2 Package information

- Epoxy meets UL94, V0
- Cooling method:C (by conduction)
- Recommended torque value:0.9 to 1.2 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

2.1 TOP3 insulated package information

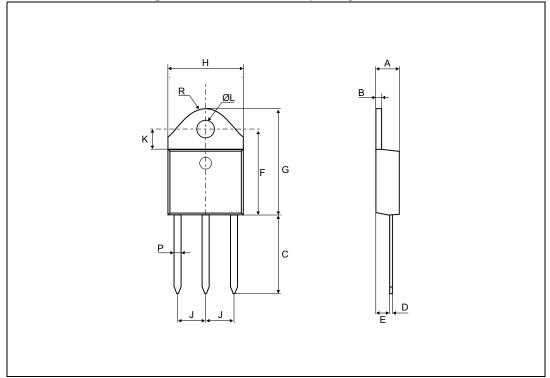


Figure 10. TOP3 insulated package outline



	Table 0. TOPS Insulated package inechanical data					
	Dimensions					
Ref.		Millimeters			Inches ⁽¹⁾	
	Тур.	Min.	Max.	Тур.	Min.	Max.
А		4.4	4.6		0.173	0.181
В		1.45	1.55		0.057	0.061
С		14.35	15.60		0.565	0.614
D		0.5	0.7		0.020	0.028
Е		2.7	2.9		0.106	0.114
F		15.8	16.5		0.622	0.650
G		20.4	21.1		0.815	0.831
Н		15.1	15.5		0.594	0.610
J		5.4	5.65		0.213	0.222
К		3.4	3.65		0.134	0.144
ØL		4.08	4.17		0.161	0.164
Р		1.20	1.40		0.047	0.055
R	4.60			0.181		

1. Values in inches are converted from mm and rounded to 4 decimal digits.



3 Ordering information

Order code	Marking	Package	Weight	Base qty.	delivery mode	
TPDV640RG	TPDV640					
TPDV840RG	TPDV840	TOP3 insulated	4.5 g	30	Tube	
TPDV1240RG	TPDV1240					

Table 7. Ordering information

4 Revision history

Date	Revision	Changes
30-Mar-2011	1	Initial release.
10-Jun-2015	2	Updated <i>Table 3</i> . Updated <i>Figure 9</i> . Format updated to current standard.

Table 8. Document revision history



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